**Product data sheet** 

## 1. General description

Ultrafast power diode in a SOT428 (DPAK) surface-mountable plastic package.

### 2. Features and benefits

- High thermal cycling performance
- Low switching losses
- · Low thermal resistance
- Soft recovery minimizes power-consuming oscillations
- Surface-mountable package

# 3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_R$	reverse voltage	DC	-	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	-	5	А
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	-	60	Α
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	-	66	Α
Static characte	eristics					
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.12	1.3	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	0.97	1.11	V
Dynamic chara	acteristics					
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	30	50	ns

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**BYV25D-600** 

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# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		K — A
2	K	cathode[1]		001aaa020
3	Α	anode		
mb	К	cathode	DPAK (SOT428)	

<sup>[1]</sup> It is not possible to connect to pin 2 of the SOT428 package

# 6. Ordering information

**Table 3. Ordering information** 

Type number	Package							
	Name	Description	Version					
BYV25D-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428					

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# 7. Limiting values

#### **Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{RRM}$	repetitive peak reverse voltage		-	600	V
$V_{RWM}$	crest working reverse voltage		-	600	V
$V_R$	reverse voltage	DC	-	600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	5	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; T <sub>mb</sub> ≤ 132 °C; square-wave pulse	-	10	A
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse; Fig. 4	-	60	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	66	Α
T <sub>stg</sub>	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

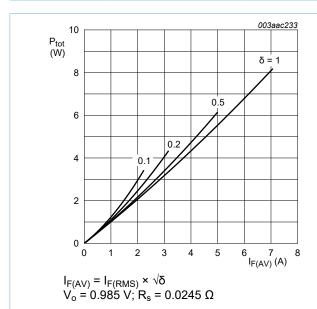


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

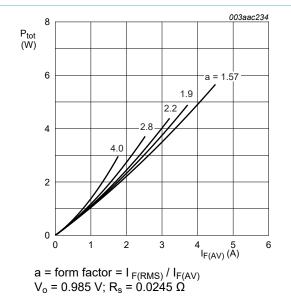
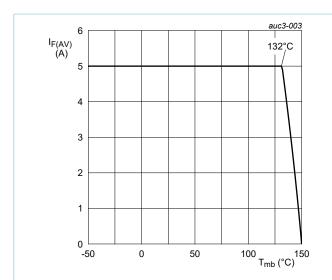


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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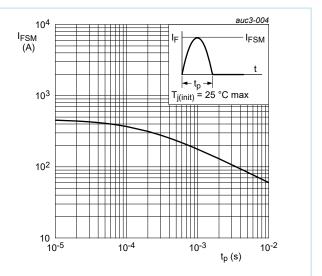


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

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### 8. Thermal characteristics

#### **Table 5. Thermal characteristics**

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5		-	-	3	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air		[1]	-	50	-	K/W

[1] device mounted on an FR4 PCB, single-sided copper, tin plated and standard footprint

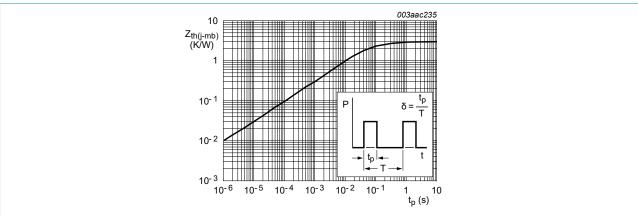


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse width

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### 9. Characteristics

#### **Table 6. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					,
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.12	1.3	V
		I <sub>F</sub> = 5 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	0.97	1.11	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	2	50	μΑ
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 100 °C	-	0.1	0.35	mA
Dynamic ch	naracteristics					,
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 100 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7	-	30	50	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	2.4	4	А
Q <sub>r</sub>	recovered charge	$I_F = 2 \text{ A}$ ; $V_R = 30 \text{ V}$ ; $dI_F/dt = 20 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7	-	30	50	nC
$V_{FR}$	forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 10 \text{ A/}\mu\text{s}; T_j = 25 ^{\circ}\text{C}$	-	3.2	-	V

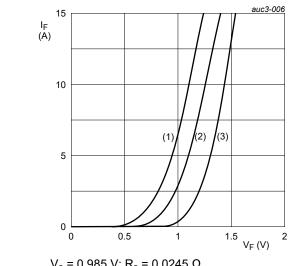
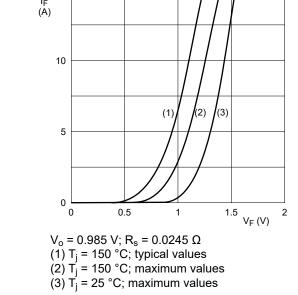


Fig. 6. Forward current as a function of forward voltage

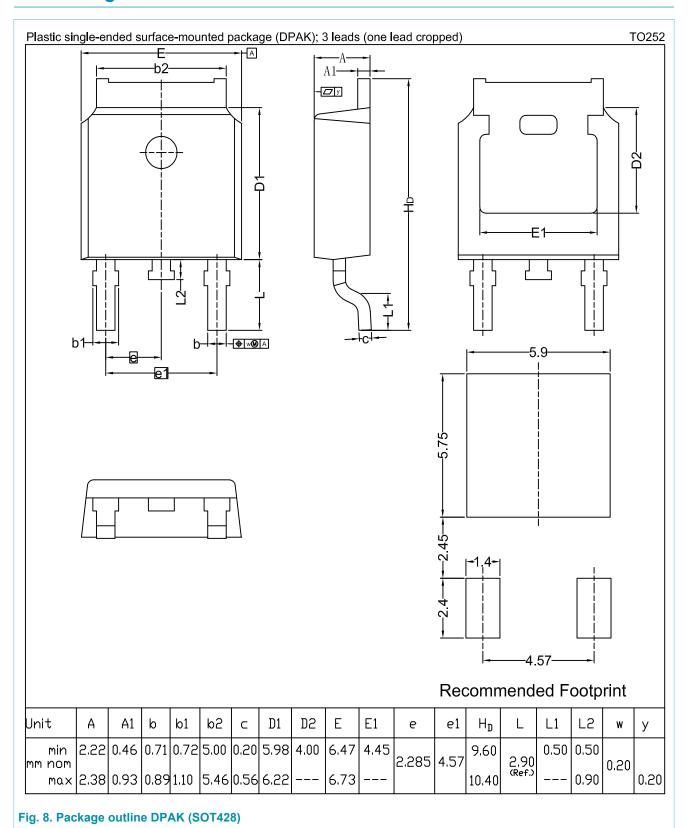


 $\mathsf{dI}_\mathsf{F}$ time 25 % 100 %  $I_{RM}$  $I_R$ 003aac562

Fig. 7. Reverse recovery definitions; ramp recovery

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## 10. Package outline



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### 11. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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**BYV25D-600** 

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